

16A 400V Fast recovery diode

1 Description

16A, 400V Ultrafast Diodes They have a low forward voltage drop and are of planar, silicon nitride passivated, ion-implanted, epitaxial construction. These devices are intended for use as energy steering/clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Their low stored charge and ultrafast recovery with soft recovery characteristics minimizes ringing and electrical noise in many power switching circuits, thus reducing power loss in the switching transistor

TO-220F provides insulation voltage rated at 2000V RMS from all three terminals to external heatsink.

2 Features

- Low power loss,
- high efficiency Low forward voltage,
- high current capability High surge capacity
- Super fast recovery times
- high voltage

3 Applications

- Switching Power Supply
- Power Switching Circuits
- General Purpose

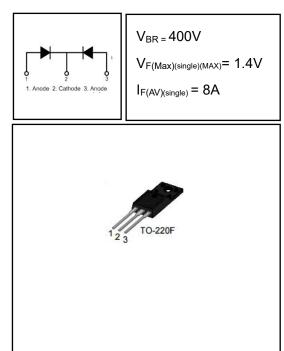
4 Electrical Characteristics

4.1 Absolute Maximum Ratings (Tc=25°C, unless otherwise noted)

PARAMETER		SYMBOL	VALUE	UNIT
Peak Repetitive Reverse Voltage		VRRM	400	V
Working Peak Reverse Voltage		V _{RWM}	400	V
DC Blocking Voltage		V _R	400	V
Average Rectified Forward Current(single)	TO-220 Tc=135℃	I _{F(AV)}	8	А
Average Rectified Forward Current(double)	TO-220F Tc=100℃		16	А
Repetitive Peak Surge Current(single)		I _{FRM}	12	А
single Nonrepetitive Peak Surge	tp=8.3ms	I _{FSM}	80	А
Avalanche Energy	L=1Hm	E _{AS}	15	mJ
Operating Junction Temperature Range		Tj	-55~150	°C
Storage Temperature Range		T _{stg}	-55~150	°C

4.2 Thermal Characteristics

PARAMETER	SYMBOL	VAL	UNIT	
FARAMETER		TO-220F	TO-220	UNIT
Thermal Resistance, Junction to Case-sink	RthJC	3.0	2.0	°C/W





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I.3 Electrical Characteristics (Tc=25°C, unless otherwise noted)						
PARAMETER	SYMBOL TEST CONDITION		MIN	TYP	MAX	UNIT
Maximum Instantaneous	VF	$I_F = 8A$	-	1.25	1.4	V
Forward Voltage		I _F = 8A, T _C = 150℃	-	-	1.20	V
		I _F = 16A	-	1.45	1.6	V
Maximum Instantaneous	I _R	V _R = 400V	-	-	5	uA
Reverse		V _R = 400V, TC = 150℃	-	-	1	mA
Maximum Reverse	trr	V _R =30V IF=1A -dI/dt=50A/us	-	25	35	ns
Recovery Time						
Total capacitance	Ctot	V _R =0V f=1MHz	-	75	-	pF
DC Blocking Voltage	V _{BR}	I _R =100uA	410	440	-	V

DEFINITIONS

VF = Instantaneous forward voltage (pw = 300µs, D = 2%).

IR = Instantaneous reverse current.

 $R\theta JC$ = Thermal resistance junction to case.

pw = pulse width.

D = duty cycle.

Typical characteristics diagrams 5

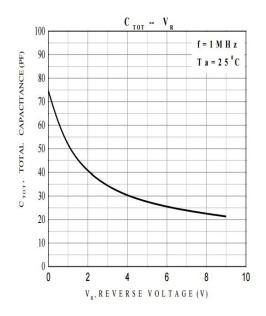


FIGURE 1. Total capacitance vs Voltage

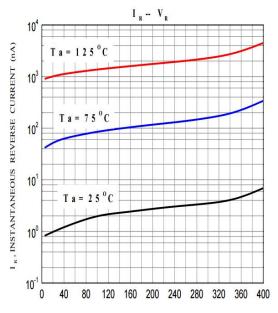
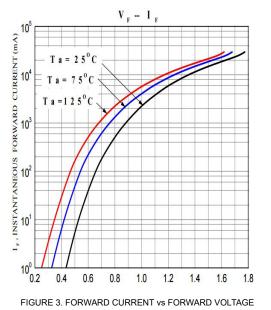


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE



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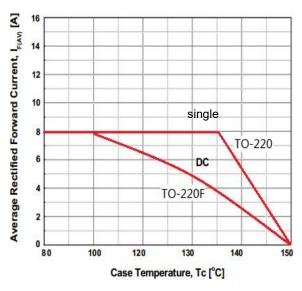


FIGURE 4. CURRENT DERATING CURVE

6 Typical Test Circuit and Waveform

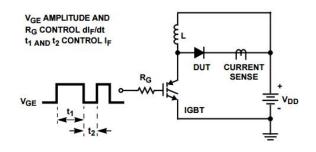


FIGURE 5. trr TEST CIRCUIT

 $\begin{array}{l} {\sf R} < 0.1 \Omega \\ {\sf E}_{{\sf AVL}} = 1/2 L l^2 \left[{\sf V}_{{\sf R}({\sf AVL})} / ({\sf V}_{{\sf R}({\sf AVL})} - {\sf V}_{{\sf DD}}) \right] \end{array}$

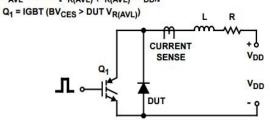


FIGURE 7. AVALANCHE ENERGY TEST CIRCUIT FIGURE

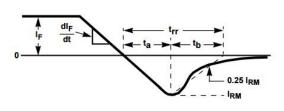


FIGURE 6. trr WAVEFORMS AND DEFINITIONS

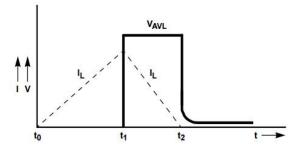


FIGURE8. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

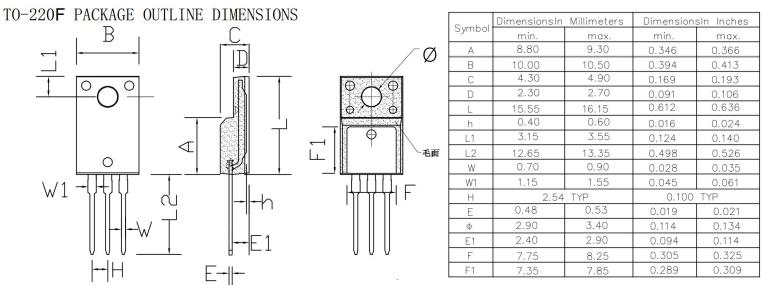


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8 **Product Specifications and Packaging Models**

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Product Model	Package Type	Mark Name	RoHS	Package	Quantity
MUR1640CT	TO-220	MUR1640CT	Pb-free	Tube	1000/box
MURF1640CT	TO-220F	MURF1640CT	Pb-free	Tube	1000/box

9 Dimensions



10 Attentions

- Jiangsu Donghai Semiconductor Co.,Ltd.. reserves the right to change the specification without prior notice! The customer should obtain the latest version of the information before making the order and verify that the information is complete and up to date.
- It is the responsibility of the purchaser for any failure or failure of any semiconductor product under certain conditions. It is the responsibility of the purchaser to comply with safety standards and to take safety measures in the system design and machine manufacturing of Jiangsu Donghai Semiconductor Co.,Ltd. products in order to avoid potential risk of failure. Injury or property damage.
- Product promotion is endless, our company will be dedicated to provide customers with better products.

11 Appendix

Revision history:

Date	REV.	Description	Page
2017.07.22	1.0	Original	